

TECHNICAL DATA
DATA SHEET 680, REV. B

HERMETIC POWER SCHOTTKY RECTIFIER Very Low Forward Voltage Drop

DESCRIPTION: A 45 VOLT, 15 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC LCC-5 PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_C = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	45	Volts
MAXIMUM DC OUTPUT CURRENT (@ $T_C = 100^\circ\text{C}$)	I_o	15	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ($t = 8.3\text{ms}$, Sine)	I_{FSM}	150	Amps
MAXIMUM JUNCTION CAPACITANCE ($V_r = 5\text{V}$, $T_J = 25^\circ\text{C}$, $f_{SIG} = 1\text{MHz}$, $V_{SIG} = 50\text{mV P-P}$)	C_T	800	pF
MAXIMUM THERMAL RESISTANCE (Junction to Case)	$R_{\theta JC}$	2.65	$^\circ\text{C/W}$
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 150	$^\circ\text{C}$

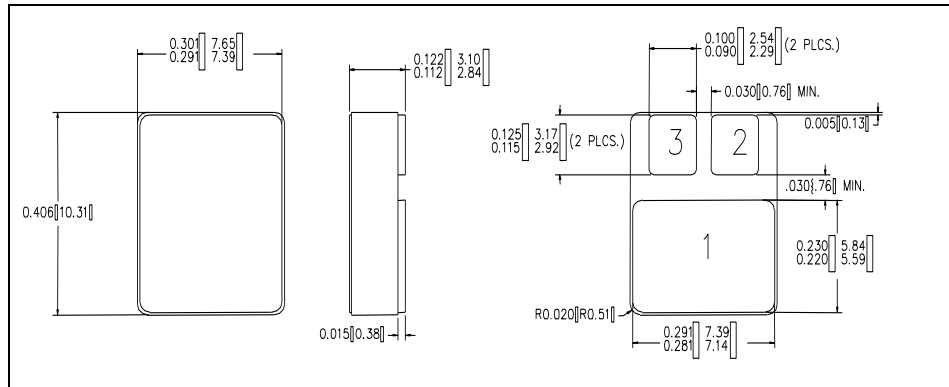
ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ($I_f = 15\text{ Amps}$) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	V_f	0.65 0.60	Volts
MAXIMUM REVERSE CURRENT (I_r @ 45 V PIV) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	I_r	1.5 70	mA

Note: V_f Curves are shown for die only.

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MECHANICAL DIMENSIONS: IN Inches / mm

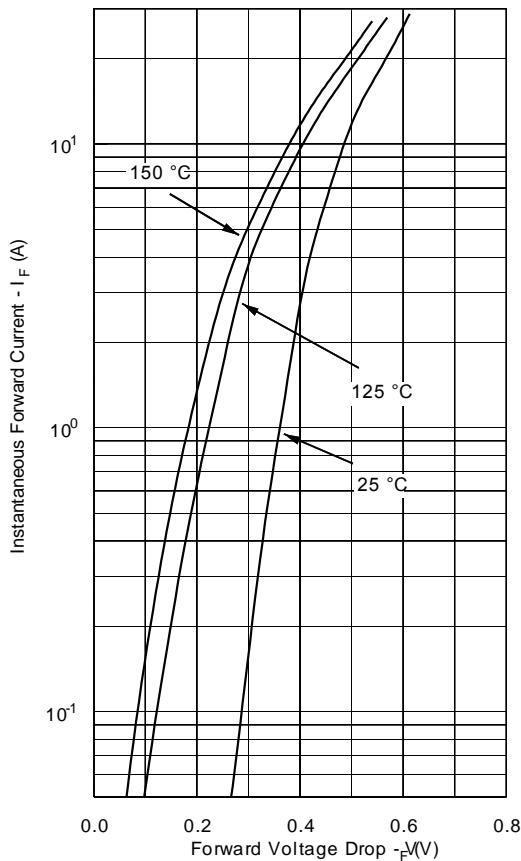


LCC-5

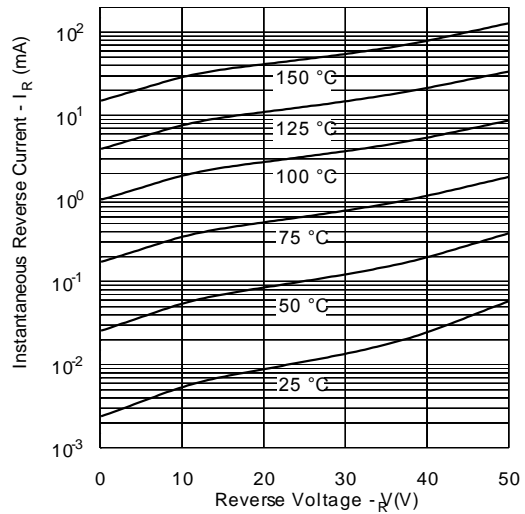
PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
DUAL RECTIFIER, COMMON CATHODE (P)	CATHODE	ANODE	ANODE

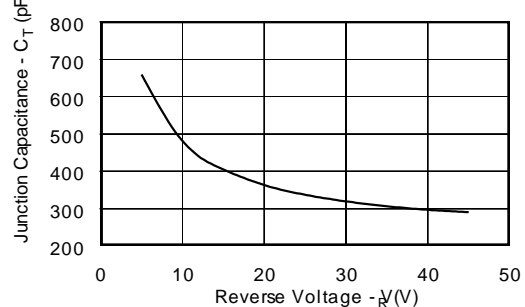
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



**TECHNICAL DATA
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